



## Internal Quantum Efficiency of III-Nitride Light-Emitting Diodes

Guest Editors:

**Prof. Dr. Jong-In Shim**

Department of Electronics and  
Communication Engineering and  
Department of Photonics and  
Nanoelectronics, Hanyang  
University ERICA, Ansan,  
Gyeonggi-do 15588, Korea

**Prof. Dr. Dong-Soo Shin**

Department of Physics, Yonsei  
University, Seoul 03722, Korea

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### Message from the Guest Editors

Dear Colleagues,

III-nitride light-emitting diodes (LEDs) have been of great importance in recent years. Further expansion of LED applications depend on energy efficiency, fabrication cost, and reliability. A major challenge for III-nitride LEDs is delivering the highest efficiency performance at the current densities and temperatures for the intended applications.

The internal quantum efficiency (IQE), defined as the ratio of the number of photons emitted from the active region to the number of electrons injected into the device, is a key performance parameter that represents the carrier dynamics as well as the quality of semiconductor epitaxial layers. In this Special Issue, we intend to focus on technical hurdles relevant to the IQEs of III-nitride LEDs emitting from ultraviolet to visible spectral ranges, covering such topics as the IQE measurement methods, microscopic or macroscopic models describing the optoelectronic performances, characterization techniques, efficiency droop phenomena, structural dependences on epitaxial layers, current crowding, or chip size, and short- or long-term reliability.

Prof. Dr. Jong-In Shim

Prof. Dr. Dong-Soo Shin

*Guest Editors*





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## Editor-in-Chief

**Prof. Dr. Giulio Nicola Cerullo**  
Dipartimento di Fisica,  
Politecnico di Milano, Piazza L.  
da Vinci 32, 20133 Milano, Italy

## Message from the Editor-in-Chief

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Applied Sciences Editorial Office  
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